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## GPIO

General Purpose Input/Output pins on the Raspberry Pi

### Overview

This page expands on the technical features of the GPIO pins available on BCM2835 in general. For usage examples, see [GPIO usage](#). When reading this page, reference should be made to the BCM2835 ARM peripherals [data sheet](#), section 6.

GPIO pins can be configured as either general-purpose input, general-purpose output, or as one of up to six special alternate settings, the functions of which are pin-dependent.

There are three GPIO banks on BCM2835.

Each of the three banks has its own VDD input pin. On Raspberry Pi, all GPIO banks are supplied from 3.3V. **Connection of a GPIO to a voltage higher than 3.3V will likely destroy the GPIO block within the SoC.**

A selection of pins from Bank 0 is available on the P1 header on Raspberry Pi.

### GPIO pads

The GPIO connections on the BCM2835 package are sometimes referred to in the peripherals data sheet as "pads" — a semiconductor design term meaning 'chip connection to outside world'.

The pads are configurable CMOS push-pull output drivers/input buffers. Register-based control settings are available for:

- Internal pull-up / pull-down enable/disable
- Output [drive strength](#)
- Input Schmitt-trigger filtering

### Power-on states

All GPIO pins revert to general-purpose inputs on power-on reset. The default pull states are also applied, which are detailed in the alternate function table in the ARM peripherals datasheet. Most GPIOs have a default pull applied.

### Interrupts

Each GPIO pin, when configured as a general-purpose input, can be configured as an interrupt source to the ARM. Several interrupt generation sources are configurable:

- Level-sensitive (high/low)
- Rising/falling edge
- Asynchronous rising/falling edge

Level interrupts maintain the interrupt status until the level has been cleared by system software (e.g. by servicing the attached peripheral generating the interrupt).

The normal rising/falling edge detection has a small amount of synchronisation built into the detection. At the system clock frequency, the pin is sampled with the criteria for generation of an interrupt being a stable transition within a three-cycle window, i.e. a record of '1 0 0' or '0 1 1'. Asynchronous detection bypasses this synchronisation to enable the detection of very narrow events.

## Alternative functions

Almost all of the GPIO pins have alternative functions. Peripheral blocks internal to BCM2835 can be selected to appear on one or more of a set of GPIO pins, for example the I2C busses can be configured to at least 3 separate locations. Pad control, such as drive strength or Schmitt filtering, still applies when the pin is configured as an alternate function.

## Voltage specifications

The following table gives the various voltage specifications for the GPIO pins, it was extracted from the Compute Module datasheet [here](#).

Symbol	Parameter	Conditions	Min	Typical	Max	Unit
$V_{IL}$	Input Low Voltage	VDD IO = 1.8V	-	-	0.6	V
		VDD IO = 2.7V	-	-	0.8	V
		VDD IO = 3.3V	-	-	0.9	V
$V_{IH}$	Input high voltage <sup>a</sup>	VDD IO = 1.8V	1.0	-	-	V
		VDD IO = 2.7V	1.3	-	-	V
		VDD IO = 3.3V	1.6	-	-	V
$I_{IL}$	Input leakage current	TA = +85°C	-	-	5	µA
$C_{IN}$	Input capacitance	-	-	5	-	pF
$V_{OL}$	Output low voltage <sup>b</sup>	VDD IO = 1.8V, IOL = -2mA	-	-	0.2	V
		VDD IO = 2.7V, IOL = -2mA	-	-	0.15	V
		VDD IO = 3.3V, IOL = -2mA	-	-	0.14	V
$V_{OH}$	Output high voltage <sup>b</sup>	VDD IO = 1.8V, IOH = 2mA	1.6	-	-	V
		VDD IO = 2.7V, IOH = 2mA	2.5	-	-	V
		VDD IO = 3.3V, IOH = 2mA	3.0	-	-	V
$I_{OL}$	Output low current <sup>c</sup>	VDD IO = 1.8V, VO = 0.4V	12	-	-	mA

Symbol	Parameter	Conditions	Min	Typical	Max	Unit
		VDD IO = 2.7V, VO = 0.4V	17	-	-	mA
		VDD IO = 3.3V, VO = 0.4V	18	-	-	mA
I <sub>OH</sub>	Output high current <sup>c</sup>	VDD IO = 1.8V, VO = 1.4V	10	-	-	mA
		VDD IO = 2.7V, VO = 2.3V	16	-	-	mA
		VDD IO = 3.3V, VO = 2.3V	17	-	-	mA
R <sub>PU</sub>	Pullup resistor	-	50	-	65	kΩ
R <sub>PD</sub>	Pulldown resistor	-	50	-	65	kΩ

<sup>a</sup> Hysteresis enabled

<sup>b</sup> Default drive strength (8mA)

<sup>c</sup> Maximum drive strength (16mA)

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